# Onsemi

# Voltage Regulator - Low Iq, Low Dropout, Power Good Output

1.2 A

# **NCV8187**

The NCV8187 is 1.2 A LDO Linear Voltage Regulator. It is a very stable and accurate device with low quiescent current consumption (typ. 30 µA over the full temperature range), low dropout, low output noise and very good PSRR. The regulator incorporates several protection features such as Thermal Shutdown, Soft Start, Current Limiting and also Power Good Output signal for easy MCU interfacing.

#### Features

- Operating Input Voltage Range: 1.5 V to 5.5 V
- Adjustable and Fixed Voltage Options Available: 0.8 V to 5.2 V
- Low Quiescent Current: typ. 30 µA over Temperature
- $\pm 2\%$  Accuracy Over Full Load, Line and Temperature variations
- PSRR: 75 dB at 1 kHz
- Low Noise: typ. 15  $\mu V_{RMS}$  from 10 Hz to 100 kHz
- Stable With Small 10 µF Ceramic Capacitor
- Soft-start to Reduce Inrush Current and Overshoots
- Thermal Shutdown and Current Limit Protection
- Power Good Signal Extends Application Range
- Available in WDFN6 and WDFNW6 2x2, DFN6 3x3, DFNW6 3x3, DFNW8 3x3 and DPAK-5 with Wettable Flank (pin edge plating)
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Typical Applications**

- Wireless Chargers and Portable Equipment
- Smart Camera and Robotic Vision Systems
- Telecommunication and Networking Systems
- Infotainment and Cluster
- Modular Platforms for Dashboard Display
- Internet Connection Sharing (ICS) Gateway Server Applications
- General Purpose Automotive

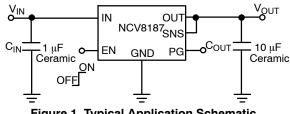
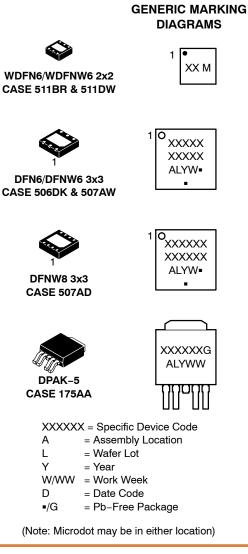


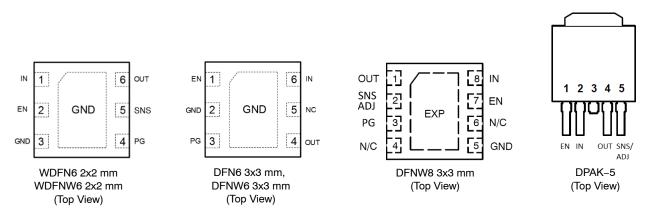
Figure 1. Typical Application Schematic



#### ORDERING INFORMATION

See detailed ordering and shipping information on page 12 of this data sheet.

## **PIN FUNCTION CONNECTION**



#### Figure 2. Pin Function Connection

#### **PIN FUNCTION DESCRIPTION**

Pin No. WDFN6 & WDFNW6 2x2	Pin No. DFN6 & DFNW6 3x3	Pin No. DFNW8 3x3	Pin No. DPAK-5	Pin Name	Description
1	6	8	2	IN	Input pin. A small capacitor is needed from this pin to ground to assure stability
6	4	1	4	OUT	Regulated output voltage pin. A small 10 $\mu\text{F}$ ceramic capacitor is needed from this pin to ground to assure stability
3, EXP	2, EXP	5, EXP	TAB	GND	Power supply ground
2	1	7	1	EN	Enable pin. Driving this pin high turns on the regulator. Driving EN pin low puts the regulator into shutdown mode
5	-	2 / -	5 / -	SNS	Sense pin. Connect this pin to regulated output voltage
-	-	- / 2	- / 5	ADJ	Adjustable feedback voltage input. Connect this pin to external resistor divider for desired voltage output
4	3	3	-	PG	Power Good, open collector. Use 10 k $\Omega$ to 100 k $\Omega$ pull–up resistor connected to output or input voltage
-	5	4, 6	-	NC	No connection. This pin can be tied to ground to improve thermal dissipation or left disconnected

#### **ABSOLUTE MAXIMUM RATINGS**

Ratings	Symbol	Value	Unit
Input Voltage (Note 1)	V <sub>IN</sub>	-0.3 to 6	V
Enable Voltage	V <sub>EN</sub>	-0.3 to 6	V
Power Good Current	I <sub>PG</sub>	30	mA
Power Good Voltage	V <sub>PG</sub>	-0.3 to 6	V
Output Voltage	V <sub>OUT</sub>	–0.3 to V <sub>IN</sub> + 0.3 (max. 5.5)	V
Output Short Circuit Duration	t <sub>SC</sub>	Indefinite	s
Maximum Junction Temperature	T <sub>J(MAX)</sub>	150	°C
Storage Temperature	T <sub>STG</sub>	–55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD <sub>HBM</sub>	2000	V
ESD Capability, Machine Model (Note 2)	ESD <sub>MM</sub>	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114) ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)

#### **THERMAL CHARACTERISTICS**

Rating	Symbol	Value	Unit
THERMAL CHARACTERISTICS, WDFN6, 2x2, 0.65 PITCH PACKA	GE		•
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{ hetaJA}$	51	°C/W
Thermal Resistance, Junction-to-Case (top)	R <sub>θJC(top)</sub>	142	°C/W
Thermal Resistance, Junction-to-Case (bottom) (Note 4)	R <sub>θJC(bot)</sub>	7.8	°C/W
Thermal Resistance, Junction-to-Board	$R_{\theta JB}$	125	°C/W
Characterization Parameter, Junction-to-Top	$\Psi_{JT}$	2.0	°C/W
Characterization Parameter, Junction-to-Board	$\Psi_{JB}$	7.7	°C/W
THERMAL CHARACTERISTICS, DFN6 / DFNW6, 3x3, 0.95 PITCH	PACKAGES		
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{ hetaJA}$	50	°C/W
Thermal Resistance, Junction-to-Case (top)	R <sub>θJC(top)</sub>	142	°C/W
Thermal Resistance, Junction-to-Case (bottom) (Note 4)	R <sub>θJC(bot)</sub>	7.9	°C/W
Thermal Resistance, Junction-to-Board	R <sub>θJB</sub>	125	°C/W
Characterization Parameter, Junction-to-Top	$\Psi_{JT}$	2.0	°C/W
Characterization Parameter, Junction-to-Board	$\Psi_{JB}$	7.5	°C/W

3. The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a high-K board, following the JEDEC51.7

guidelines with assumptions as above, in an environment described in JESD51–2a. The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the IC exposed pad. Test description can be found in the ANSI SEMI standard G30–88. 4.

Parameter	Test Conditions			Symbol	Min	Тур	Max	Unit
Operating Input Voltage				VIN	1.5	-	5.5	V
Output Voltage Accuracy	$-40^{\circ}C \le T_J \le 150^{\circ}C$ ,	V <sub>OUT</sub> <	1.7 V	V <sub>OUT</sub>	–35 mV	-	+35 mV	V
	V <sub>OUT</sub> +1 V < V <sub>IN</sub> < 5.5 V, 0 mA < I <sub>OUT</sub> < 1.2 A	5 V, V <sub>OUT</sub> ≥ 1.7 V			-2%	-	+2%	
Reference Voltage				V <sub>REF</sub>	-	0.8	-	V
Line Regulation	$V_{OUT}$ + 1 V $\leq$ V <sub>IN</sub> $\leq$ 5.5 V, I <sub>O</sub>	<sub>UT</sub> = 1 mA		Reg <sub>LINE</sub>	-	40	-	μV/V
Load Regulation	I <sub>OUT</sub> = 0 mA to 1.2 A			Reg <sub>LOAD</sub>	-	2	-	μV/m/
Dropout Voltage	$V_{DO} = V_{IN} - (V_{OUT(NOM)} - 3)$	%)	1.2 V - 1.4 V	V <sub>DO</sub>	-	325	495	mV
	I <sub>OUT</sub> = 1.2 A		1.5 V – 1.7 V	-	-	240	400	
			1.8 V – 2.7 V	-	-	200	335	
			2.8 V – 3.2 V	-	-	165	250	
			3.3 V – 4.9 V		-	150	220	
			5 V		-	120	180	
Maximum Output Current	(Note 7)		I <sub>OUT</sub>	1300	1750	-	mA	
Short Circuit Current	(Note 7)			I <sub>SC</sub>	-	1850	-	mA
Disable Current	V <sub>EN</sub> = 0 V		I <sub>DIS</sub>	-	0.1	5.0	μA	
Quiescent Current	I <sub>OUT</sub> = 0 mA		l <sub>Q</sub>	-	30	45	μA	
Ground Current	I <sub>OUT</sub> = 1.2 A			I <sub>GND</sub>	-	2	-	mA
Power Supply Rejection Ratio			PSRR	-	75	-	dB	
Output Noise Voltage	V <sub>OUT</sub> = 1.8 V, I <sub>OUT</sub> = 10 mA,	f = 10 Hz	to 100 kHz	V <sub>N</sub>	-	15	-	μV <sub>rm</sub>
Enable Input Threshold	Voltage increasing			V <sub>EN_HI</sub>	0.9	-	-	V
Voltage	Voltage decreasing			V <sub>EN_LO</sub>	_	-	0.3	
EN Pin Current	V <sub>EN</sub> = 5.5 V				_	100	_	nA
Active Output Discharge Resistance	V <sub>IN</sub> = 5.5 V, V <sub>EN</sub> = 0 V			R <sub>DIS</sub>	-	120	-	Ω
Power Good, Output Voltage Raising				V <sub>PGup</sub>	-	92	-	%
Power Good, Output Voltage Falling			V <sub>PGdw</sub>	-	80	-	%	
Power Good Output Voltage Low	I <sub>PG</sub> = 6 mA, Open drain		V <sub>PGlo</sub>	-	0.14	0.4	V	
Thermal Shutdown Temperature (Note 5)	Temperature increasing from	1 T <sub>J</sub> = +25	°C	T <sub>SD</sub>	-	170	-	°C
Thermal Shutdown Hysteresis (Note 5)	Temperature falling from TSI	C		T <sub>SDH</sub>	-	15	-	°C

ELECTRICAL CHARACTERISTICS – WDFN6 2x2, WDFNW6 2x2, DFN6 3x3 AND DFNW6 3x3 ( $-40^{\circ}C \le T_{J} \le 150^{\circ}C$ ;
$V_{IN} = V_{OLIT} + 1.0 V$ ; $I_{OLIT} = 10 \text{ mA}$ , $C_{IN} = 1 \mu$ F, $C_{OLIT} = 10 \mu$ F, unless otherwise noted. Typical values are at $T_{I} = +25^{\circ}$ C. (Note 6))

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Guaranteed by design and characterization.

6. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at T<sub>J</sub> =

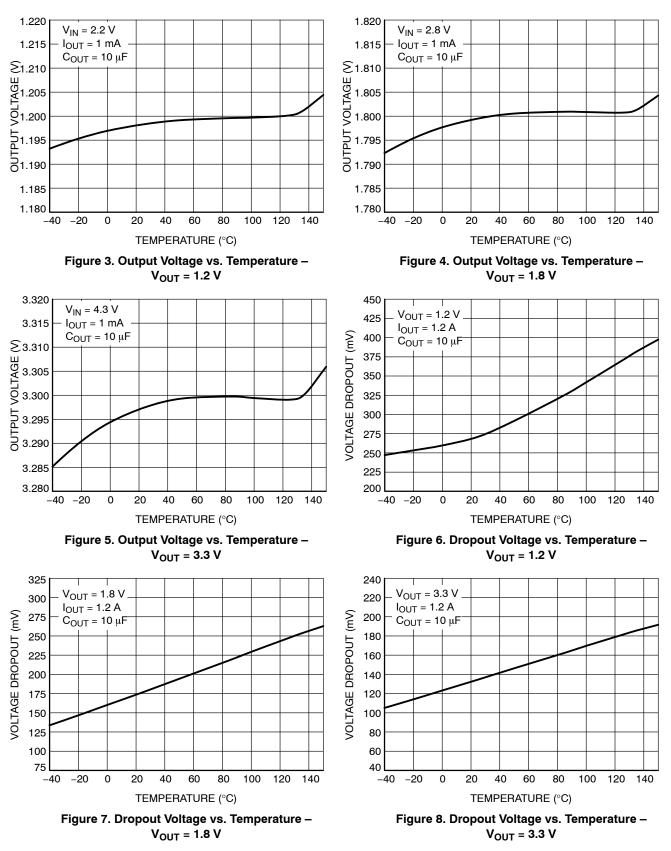
T<sub>A</sub> = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 7. Respect SOA.

Parameter	Test Conditions			Symbol	Min	Тур	Max	Unit
Operating Input Voltage				VIN	1.5	_	5.5	V
Output Voltage Accuracy	$-40^{\circ}C \le T_{J} \le 150^{\circ}C,$ $V_{OUT} < 1.7 V$		1.7 V	V <sub>OUT</sub>	–35 mV	-	+35 mV	V
	V <sub>OUT</sub> + 1 V < V <sub>IN</sub> < 5.5 V, 0 mA < I <sub>OUT</sub> < 1 A	$V_{OUT} \ge$	1.7 V		-2%	-	+2%	
Reference Voltage			V <sub>REF</sub>	-	1.2	-	V	
Line Regulation	$V_{OUT}$ + 1 V $\leq$ V <sub>IN</sub> $\leq$ 5.5 V, I <sub>OI</sub>	<sub>UT</sub> = 1 mA		Reg <sub>LINE</sub>	-	40	-	μV/V
Load Regulation	I <sub>OUT</sub> = 0 mA to 1 A			Reg <sub>LOAD</sub>	-	2	-	μV/mA
Dropout Voltage	$V_{DO} = V_{IN} - (V_{OUT(NOM)} - 3)$	%)	$1.2 \ V - 1.4 \ V$	V <sub>DO</sub>	-	295	450	mV
	I <sub>OUT</sub> = 1 A		1.5 V – 1.7 V		-	220	360	
			1.8 V – 2.7 V		-	180	305	
			2.8 V – 3.2 V		-	150	225	
			$3.3 \ V - 4.9 \ V$		_	135	200	
			5 V		_	110	165	
Maximum Output Current	(Note 10), T <sub>J</sub> = 25°C		I <sub>OUT</sub>	1025	1500	1750	mA	
Maximum Output Current	(Note 10)			I <sub>OUT</sub>	1025	1500	1950	mA
Short Circuit Current	(Note 10)	(Note 10)			-	1550	-	mA
Disable Current	V <sub>EN</sub> = 0 V	V <sub>EN</sub> = 0 V			-	0.1	5.0	μA
Quiescent Current	I <sub>OUT</sub> = 0 mA	I <sub>OUT</sub> = 0 mA			_	30	45	μA
Ground Current	I <sub>OUT</sub> = 1 A			I <sub>GND</sub>	_	2	-	mA
Power Supply Rejection Ratio	$ \begin{array}{l} V_{IN} = 3.5 \ V + 100 \ mVpp \\ V_{OUT} = 2.5 \ V \\ I_{OUT} = 10 \ mA, \ C_{OUT} = 1 \ \mu F \end{array} \right. f = 1 \ kHz \\ \end{array} $		PSRR	-	75	-	dB	
Output Noise Voltage	V <sub>OUT</sub> = 1.8 V, I <sub>OUT</sub> = 10 mA,	f = 10 Hz	to 100 kHz	V <sub>N</sub>	-	15	-	$\mu V_{\text{rms}}$
Enable Input Threshold	Voltage increasing			V <sub>EN_HI</sub>	0.9	-	-	V
Voltage	Voltage decreasing			V <sub>EN_LO</sub>	-	-	0.3	
EN Pin Current	V <sub>EN</sub> = 5.5 V				_	100	-	nA
Active Output Discharge Resistance	$V_{IN} = 5.5 \text{ V}, V_{EN} = 0 \text{ V}$			R <sub>DIS</sub>	-	120	-	Ω
Power Good, Output Voltage Raising			V <sub>PGup</sub>	-	92	-	%	
Power Good, Output Voltage Falling			V <sub>PGdw</sub>	-	80	-	%	
Power Good Output Voltage Low	I <sub>PG</sub> = 6 mA, Open drain		V <sub>PGlo</sub>	-	0.14	0.4	V	
Thermal Shutdown Temperature (Note 8)	Temperature increasing from	I T <sub>J</sub> = +25	°C	T <sub>SD</sub>	-	170	-	°C
Thermal Shutdown Hysteresis (Note 8)	Temperature falling from TSI	C		T <sub>SDH</sub>	_	15	-	°C

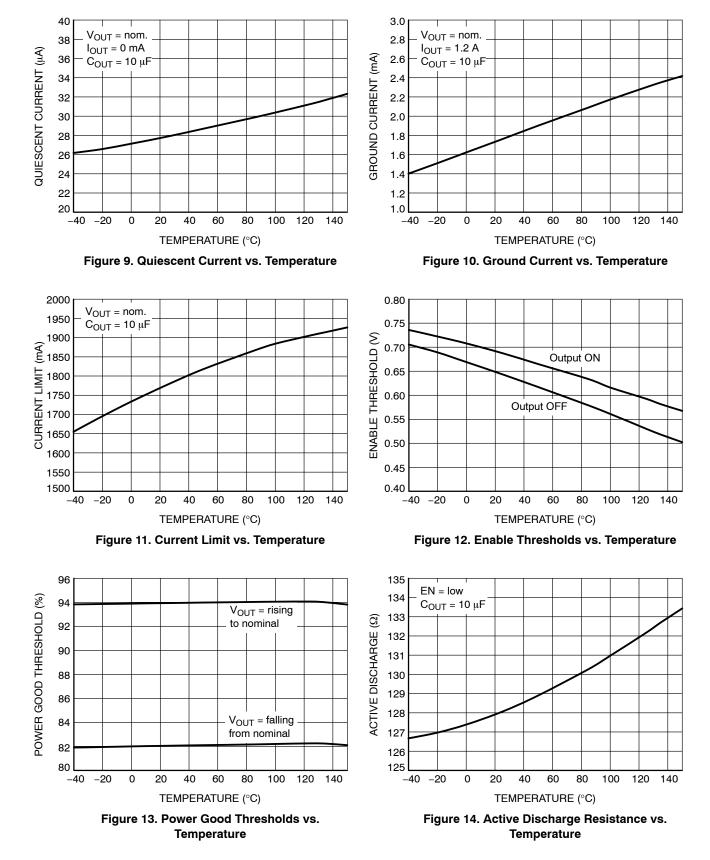
<b>ELECTRICAL CHARACTERISTICS – DFNW8 3x3 AND DPAK–5</b> (-40°C $\leq$ T <sub>J</sub> $\leq$ 150°C; V <sub>IN</sub> = V <sub>OUT</sub> + 1.0 V; I <sub>OUT</sub> = 10 mA,	
$C_{IN} = 1 \ \mu$ F, $C_{OUT} = 10 \ \mu$ F, unless otherwise noted. Typical values are at $T_{J} = +25^{\circ}$ C. (Note 9))	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

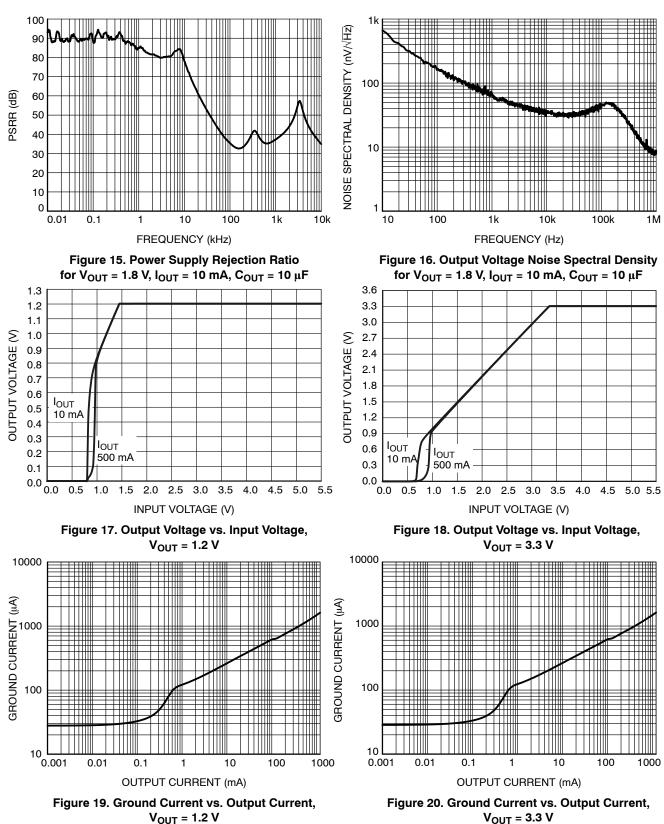
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise hold. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 8. Guaranteed by design and characterization. 9. Performance guaranteed over the indicated operating temperature range by design and/or characterization production tested at  $T_J = T_A = 25^{\circ}$ C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 10. Respect SOA.



#### **TYPICAL CHARACTERISTICS**



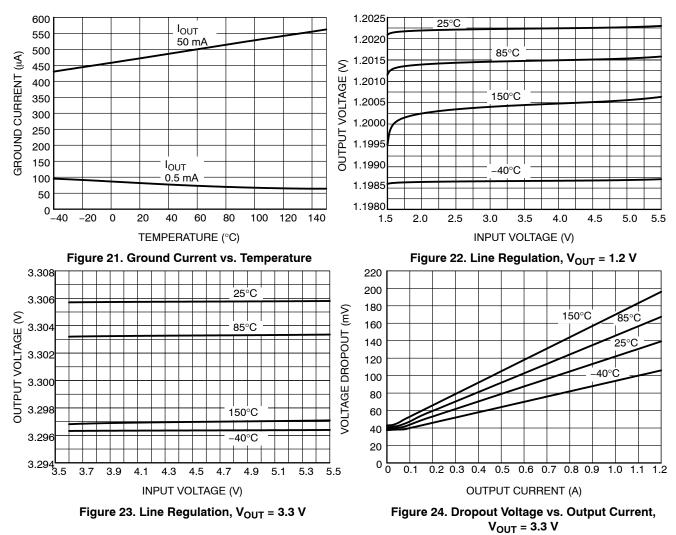
#### **TYPICAL CHARACTERISTICS**



#### **TYPICAL CHARACTERISTICS**

www.onsemi.com





#### APPLICATIONS INFORMATION

The NCV8187 is the member of new family of high output current and low dropout regulators which delivers low quiescent and ground current consumption, good noise and power supply ripple rejection ratio performance. The NCV8187 incorporates EN pin and power good output for simple controlling by MCU or logic. Standard features include current limiting, soft–start feature and thermal protection.

#### Input Decoupling (CIN)

It is recommended to connect at least 1  $\mu$ F ceramic X5R or X7R capacitor between IN and GND pin of the device. This capacitor will provide a low impedance path for any unwanted AC signals or noise superimposed onto constant input voltage. The good input capacitor will limit the influence of input trace inductances and source resistance during sudden load current changes. Higher capacitance and lower ESR capacitors will improve the overall line transient response.

#### Output Decoupling (COUT)

The NCV8187 does not require a minimum Equivalent Series Resistance (ESR) for the output capacitor. The device is designed to be stable with standard ceramics capacitors with values of 4.7  $\mu$ F or greater. Recommended capacitor for the best performance is 10  $\mu$ F. The X5R and X7R types have the lowest capacitance variations over temperature thus they are recommended.

#### **Power Good Output Connection**

The NCV8187 include Power Good functionality for better interfacing to MCU system. Power Good output is open collector type, capable to sink up to 10 mA. Recommended operating current is between 10  $\mu$ A and 1 mA to obtain low saturation voltage. External pull-up resistor can be connected to any voltage up to 5.5 V (please see Absolute Maximum Ratings table above).

#### **Power Dissipation and Heat Sinking**

The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. For reliable operation junction temperature should be limited to  $+125^{\circ}$ C. The maximum power dissipation the NCV8187 can handle is given by:

$$P_{D(MAX)} = \frac{\left[T_{J(MAX)} - T_{A}\right]}{R_{\theta JA}}$$
 (eq. 1)

The power dissipated by the NCV8187 for given application conditions can be calculated from the following equations:

$$\mathsf{P}_\mathsf{D} \approx \mathsf{V}_\mathsf{IN} \big( \mathsf{I}_\mathsf{GND} (\mathsf{I}_\mathsf{OUT}) \big) + \mathsf{I}_\mathsf{OUT} \big( \mathsf{V}_\mathsf{IN} - \mathsf{V}_\mathsf{OUT} \big) \qquad (\text{eq. 2})$$

or

$$V_{IN(MAX)} \approx \frac{P_{D(MAX)} + (V_{OUT} \times I_{OUT})}{I_{OUT} + I_{GND}}$$
 (eq. 3)

#### Hints

VIN and GND printed circuit board traces should be as wide as possible. When the impedance of these traces is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the NCV8187, and make traces as short as possible.

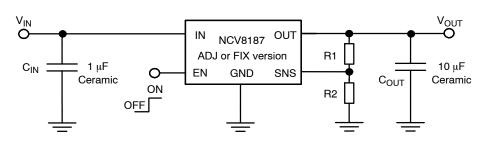
#### ADJUSTABLE VERSION

Not only adjustable version, but also any fixed version can be used to create adjustable voltage, where original fixed voltage becomes reference voltage for resistor divider and feedback loop. Output voltage can be equal or higher than original fixed option, while possible range is from 0.8 V up to 5.2 V. Picture below shows how to add external resistors to increase output voltage above fixed value.

Output voltage is then given by equation:  $V_{OUT} = V_{FIX} \times (1 + R1/R2)$ 

where  $V_{FIX}$  is voltage of original fixed version (from 0.8 V up to 5.2 V). Do not operate the device at output voltage about 5.2 V, as device can be damaged.

In order to avoid influence of current flowing into SNS pin to output voltage accuracy (SNS current varies with voltage option and temperature, typical value is 300 nA) it is recommended to use values of R1 and R2 below 500 k $\Omega$ .





Please note that output noise is amplified by  $V_{OUT} / V_{FIX}$  ratio. For example, if original 0.8 V fixed variant is used to create 3.6 V output voltage, output noise is increased 3.6/0.8 = 4.5 times and real value will be 4.5 × 15  $\mu V_{rms}$  = 67.5  $\mu V_{rms}$ . For noise sensitive applications it is

recommended to use as high fixed variant as possible – for example in case above it is better to use 3.3 V fixed variant to create 3.6 V output voltage, as output noise will be amplified only  $3.6/3.3 = 1.09 \times (16.4 \,\mu V_{rms})$ .

#### **ORDERING INFORMATION**

Device Part No.	Voltage Option	Marking	Option	Package	Shipping <sup>†</sup>
NCV8187AMT110TAG	1.1 V	PM	With Active Output	WDFN6 2x2 non WF	3,000 /
NCV8187AMT120TAG	1.2 V	PJ	Discharge	(Pb-Free)	Tape & Reel
NCV8187AMT180TAG	1.8 V	PK			
NCV8187AMT330TAG	3.3 V	PL			
NCV8187AMN120TAG	1.2 V	NA	With Active Output	DFN6 3x3 non WF	3,000 /
NCV8187AMN180TAG	1.8 V	NH	Discharge	(Pb-Free)	Tape & Reel
NCV8187AMTWADJTAG	ADJ	K2	With Active Output	WDFNW6 2x2 WF SLP	3,000 /
NCV8187AMTW080TAG	0.8 V	KG	Discharge	(Pb-Free)	Tape & Reel
NCV8187AMTW090TAG	0.9 V	KH			
NCV8187AMTW110TAG	1.1 V	KM			
NCV8187AMTW180TAG	1.8 V	KJ			
NCV8187AMTW330TAG	3.3 V	KK			
NCV8187AML120TAG	1.2 V	WD	With Active Output	DFNW6 3x3 WF SLP	3,000 /
NCV8187AML180TAG	1.8 V	WE	Discharge	(Pb-Free)	Tape & Reel
NCV8187AMLE120TCG	1.2 V	CA	With Active Output	DFNW8 3x3 WF	3,000 /
NCV8187AMLE180TCG	1.8 V	CC	Discharge	(Pb-Free)	Tape & Reel
NCV8187AMLE280TCG	2.8 V	CE			
NCV8187AMLE330TCG	3.3 V	CD			
NCV8187AMLEADJTCG	ADJ	C2			
NCV8187ADT180RKG*	1.8 V	V8187BG	With Active Output	DPAK-5	2,500 /
NCV8187ADT330RKG*	3.3 V	V8187CG	Discharge	(Pb-Free)	Tape & Reel
NCV8187ADTADJRKG*	ADJ	V8187AG			

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*Package in development.

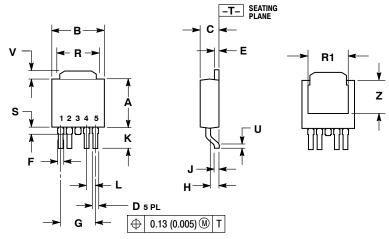




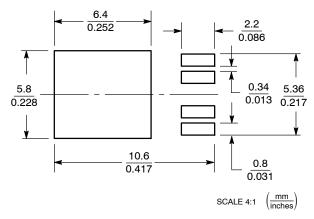
**DPAK-5, CENTER LEAD CROP** CASE 175AA **ISSUE B** 

DATE 15 MAY 2014

SCALE 1:1



#### RECOMMENDED SOLDERING FOOTPRINT\*

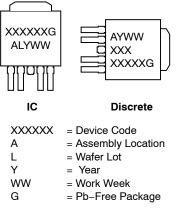


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIM	IETERS	
DIM	MIN MAX		MIN	MAX	
Α	0.235	0.245	5.97	6.22	
в	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.020	0.028	0.51	0.71	
Е	0.018	0.023	0.46	0.58	
F	0.024	0.032	0.61	0.81	
G	0.180 BSC		4.56 BSC		
н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
К	0.102	0.114	2.60	2.89	
L	0.045	BSC	1.14 BSC		
R	0.170	0.190	4.32	4.83	
<b>R</b> 1	0.185	0.210	4.70	5.33	
S	0.025	0.040	0.63	1.01	
U	0.020		0.51		
v	0.035	0.050	0.89	1.27	
Z	0.155	0.170	3.93	4.32	

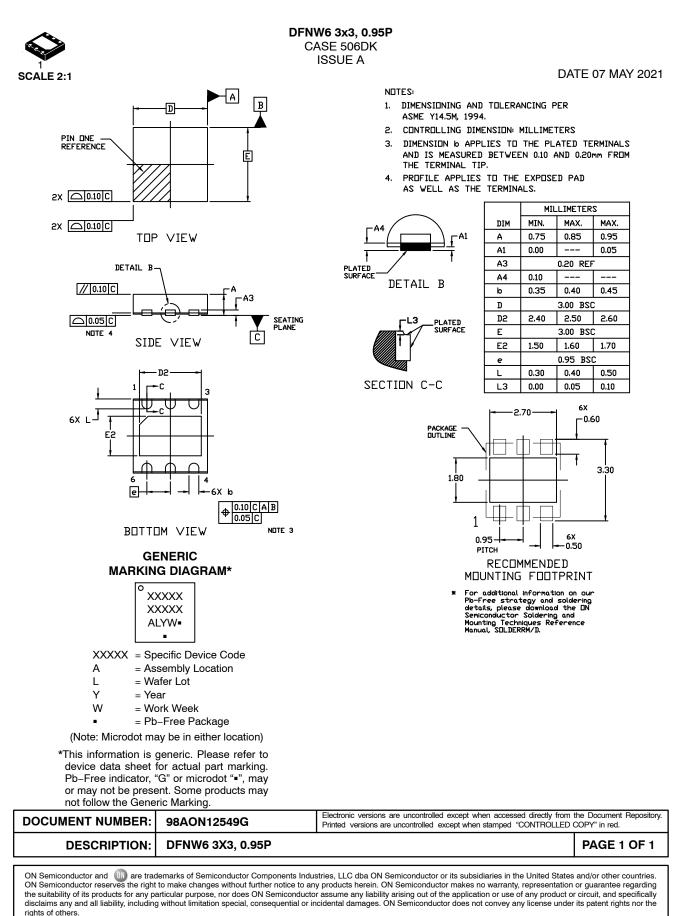
#### GENERIC **MARKING DIAGRAMS\***



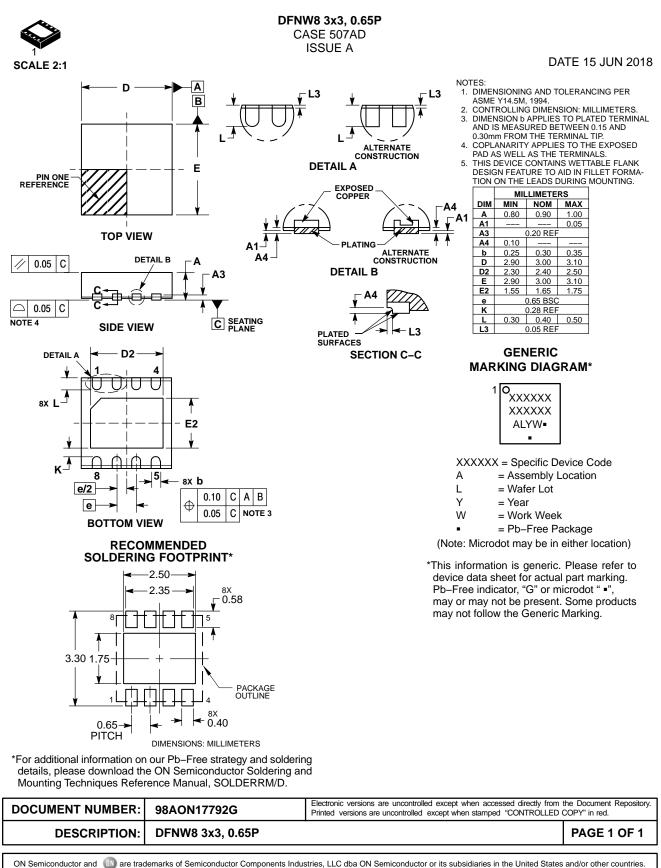
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " .", may or may not be present.

DOCUMENT NUMBER:	98AON12855D	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.					
DESCRIPTION:	DPAK-5 CENTER LEAD C	AD CROP PAGE 1 OF					
ON Semiconductor reserves the right the suitability of its products for any pa	ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the						



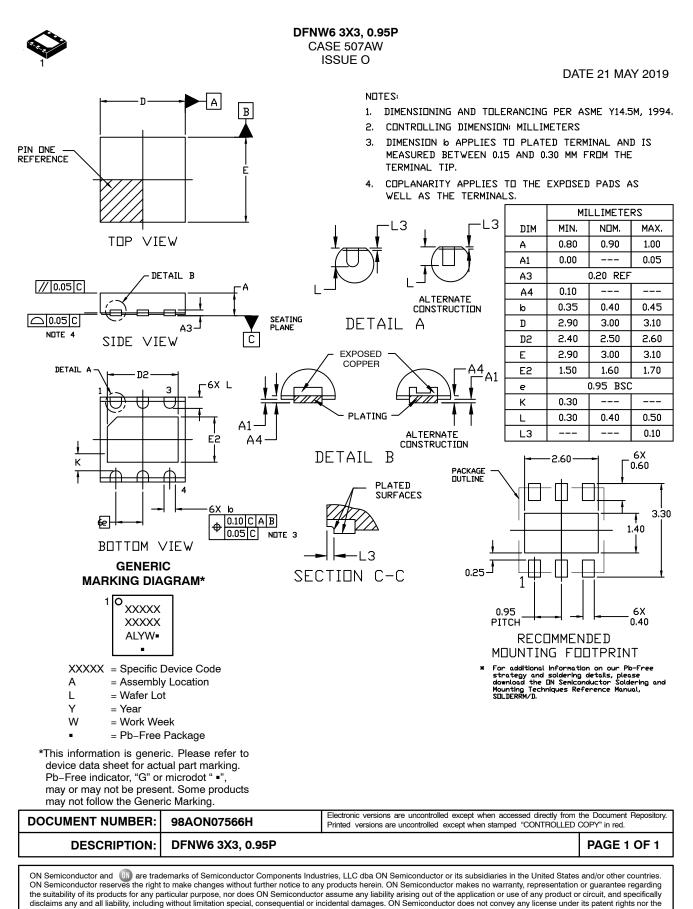






ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



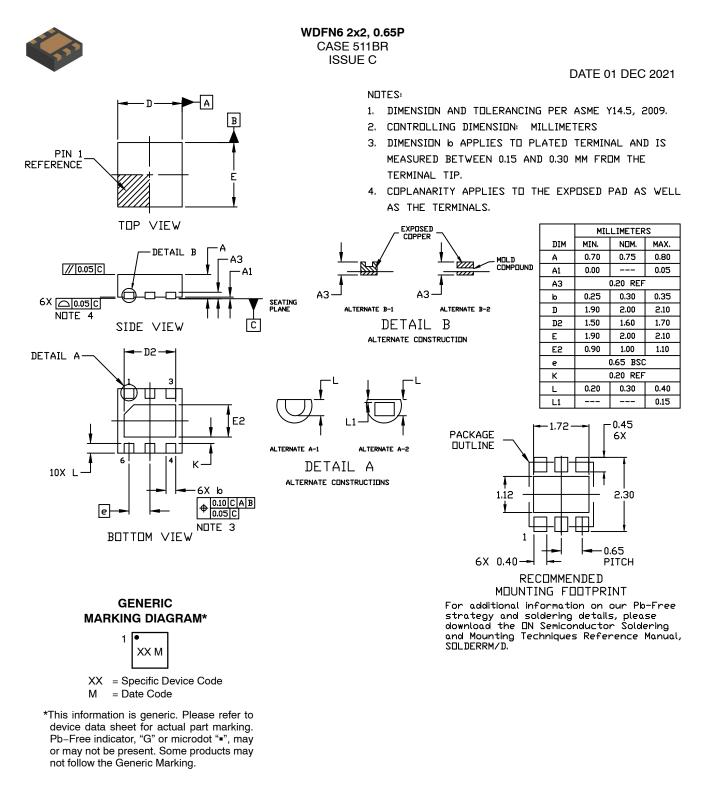


© Semiconductor Components Industries, LLC, 2018

rights of others.

#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

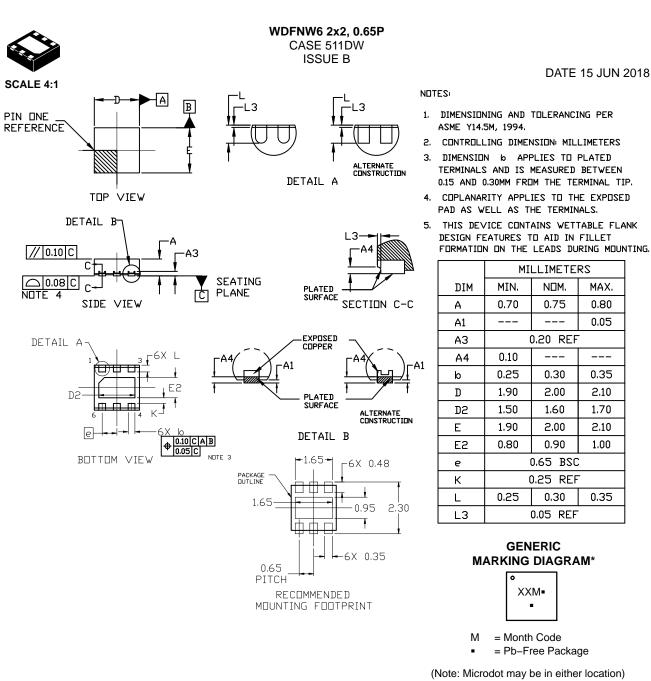
# onsemi



DOCUMENT NUMBER:	98AON55829E	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED				
DESCRIPTION:	WDFN6 2X2, 0.65P		PAGE 1 OF 1			

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON79327G	Electronic versions are uncontrolled except when accessed directly from the Document Reposito Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION:	WDFNW6 2x2, 0.65P	5P PAGE 1 OF				
ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the						

rights of others.